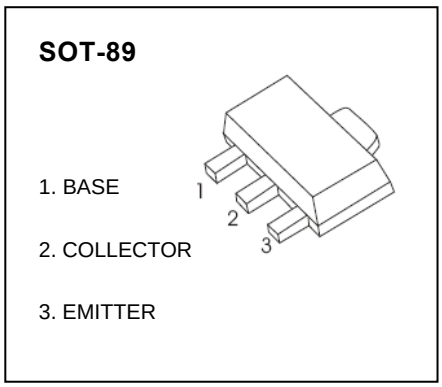
WILLAS

RoHS COMPLIANT

SOT-89 Plastic-Encapsulate Transistors

2SC4672

TRANSISTOR (NPN)



FEATURES

- Low Saturation Voltage
- Excellent h_{FE} Characteristics
- Complements the 2SA1797
- **Pb-Free package is available**
  RoHS product for packing code suffix "G"
  Halogen free product for packing code suffix "H"

MAXIMUM RATINGS (T_a=25℃ unless otherwise noted)

Symbol	Parameter	Value	Unit
V_{CBO}	Collector-Base Voltage	60	V
V_{CEO}	Collector-Emitter Voltage	50	V
V_{EBO}	Emitter-Base Voltage	6	V
I_C	Collector Current	2	A
P_C	Collector Power Dissipation	500	mW
$R_{\theta JA}$	Thermal Resistance From Junction To Ambient	250	℃/W
T_j	Junction Temperature	150	℃
T_{stg}	Storage Temperature	-55~+150	℃

ELECTRICAL CHARACTERISTICS (T_a=25℃ unless otherwise specified)

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	$V_{(BR)CBO}$	I_C=50μA,I_E=0	60			V
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	I_C=1mA,I_B=0	50			V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	I_E=50μA,I_C=0	6			V
Collector cut-off current	I_{CBO}	V_{CB}=60V,I_E=0			0.1	μA
Emitter cut-off current	I_{EBO}	V_{EB}=5V,I_C=0			0.1	μA
DC current gain	h_{FE}	V_{CE}=2V, I_C=500mA	82		390	
Collector-emitter saturation voltage	$V_{CE(sat)}$	I_C=1A,I_B=50mA			0.35	V
Transition frequency	f_T	V_{CE}=2V,I_C=0.5A, f=100MHz		210		MHz
Collector output capacitance	C_{ob}	V_{CB}=10V, I_E=0, f=1MHz		25		pF

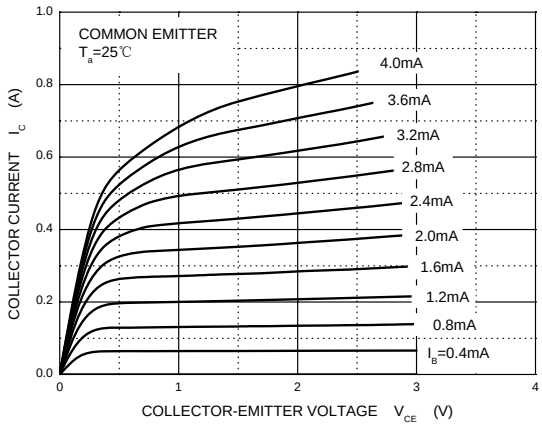
CLASSIFICATION OF h_{FE}

RANK	P	Q	R
RANGE	82 – 180	120 – 270	180 – 390
MARKING	DKP	DKQ	DKR

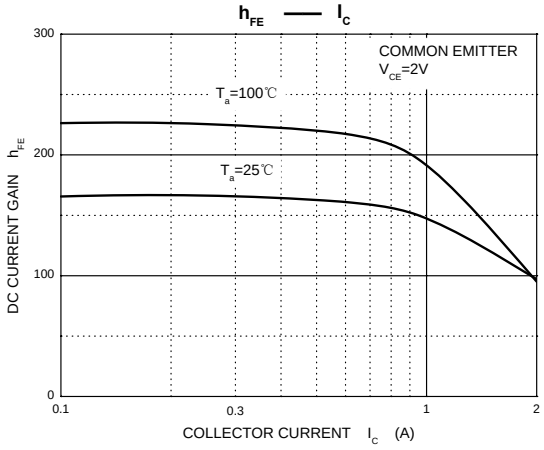
SOT-89 Plastic-Encapsulate Transistors

Typical Characterisitics

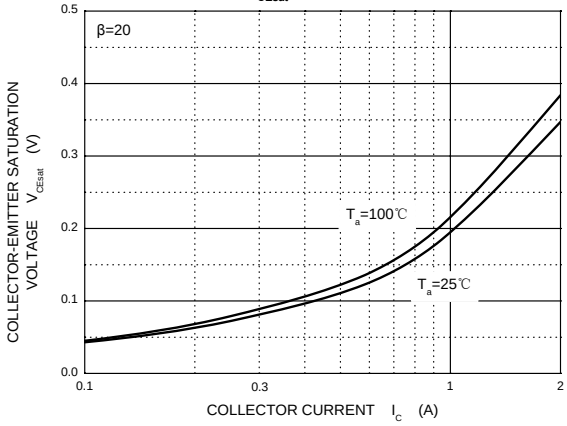
Static Characteristic



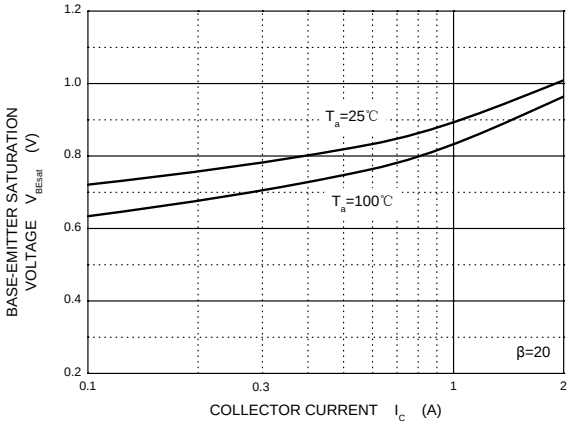
h_{FE} — I_C



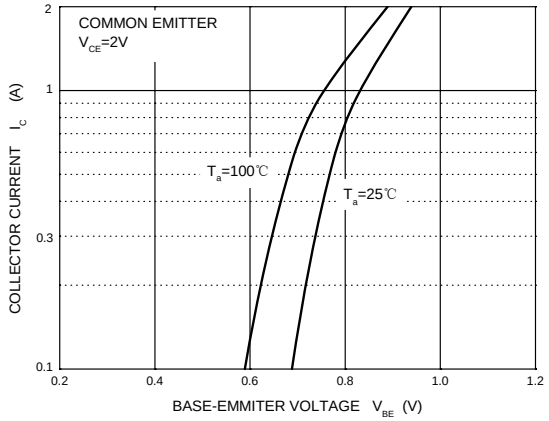
V_{CEsat} — I_C



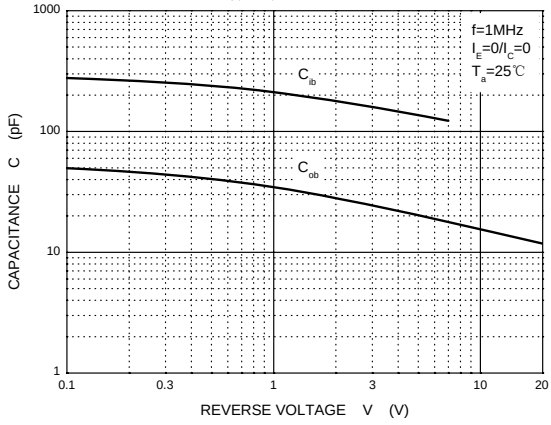
V_{BEsat} — I_C



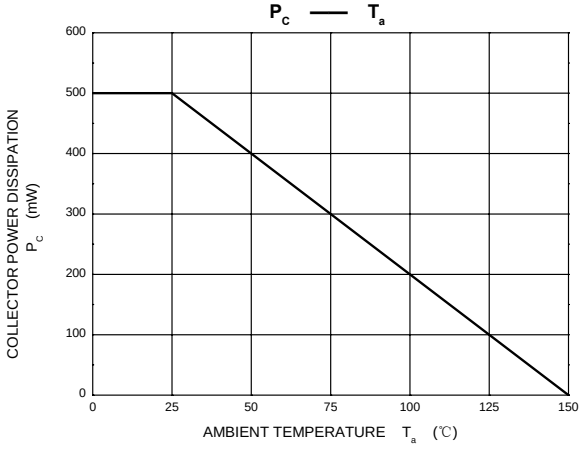
I_C — V_{BE}



C_{ob} / C_{ib} — V_{CB} / V_{EB}

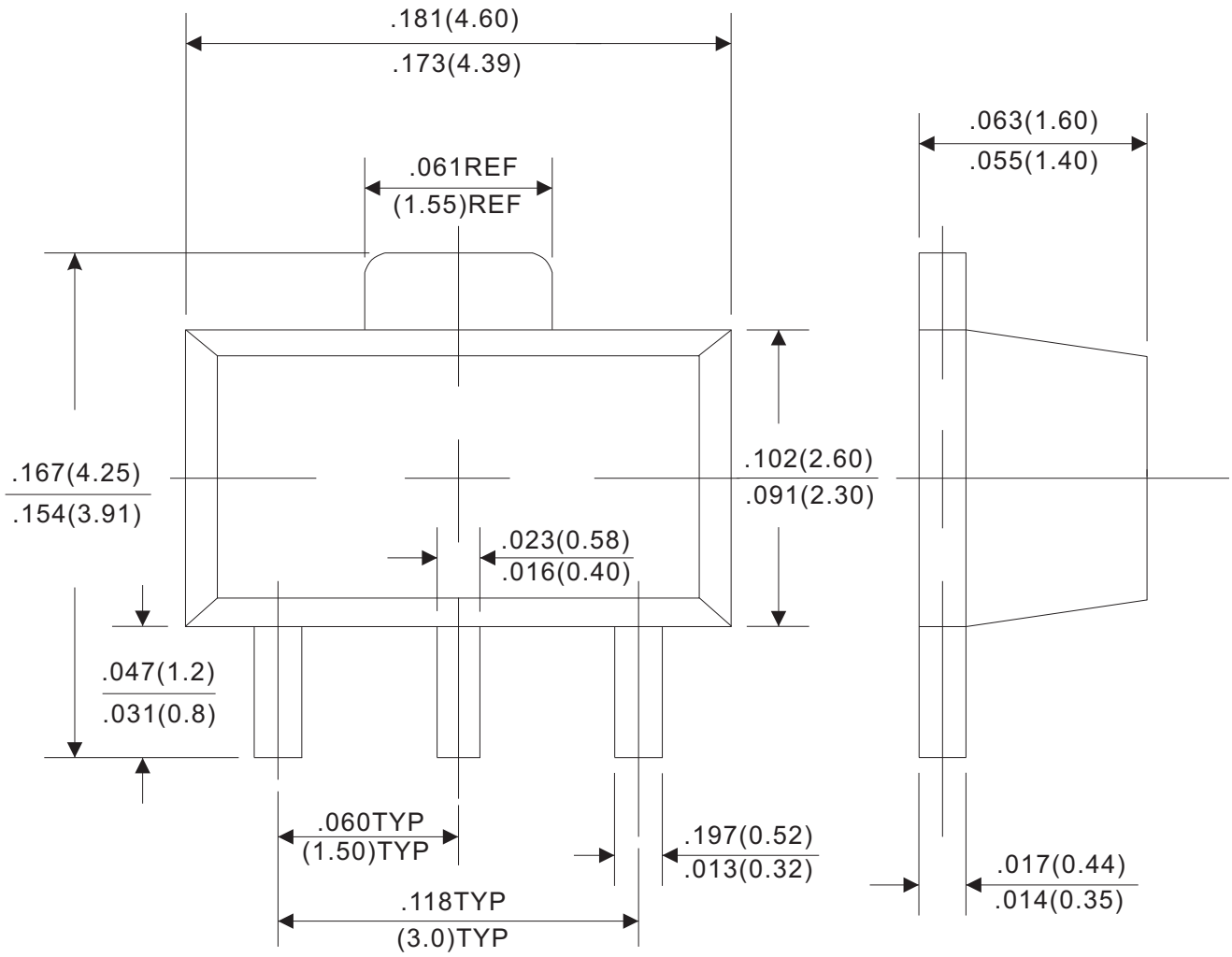


P_C — T_a



Outline Drawing

SOT-89



Dimensions in inches and (millimeters)

Rev.C